

NCE P-Channel Enhancement Mode Power MOSFET

Description

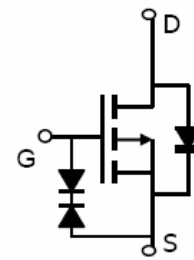
The NCE3415 uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 1.8V. This device is suitable for use as a load switch or in PWM applications. It is ESD protected.

General Features

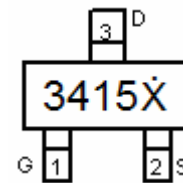
- $V_{DS} = -20V, I_D = -4A$
 $R_{DS(ON)} < 36m\Omega @ V_{GS} = -4.5V$
 $R_{DS(ON)} < 49m\Omega @ V_{GS} = -2.5V$
 ESD Rating: 2500V HBM
- High Power and current handling capability
- Lead free product is acquired
- Surface mount package

Application

- PWM application
- Load switch



Schematic diagram



Marking and pin Assignment



SOT-23 top view

Package Marking and Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|----------------|---------|----------------|-----------|------------|------------|
| 3415 X | NCE3415 | SOT-23 | Ø180mm | 8 mm | 3000 units |

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|--|----------------|------------|------|
| Drain-Source Voltage | V_{DS} | -20 | V |
| Gate-Source Voltage | V_{GS} | ±10 | V |
| Drain Current-Continuous | I_D | -4 | A |
| Drain Current-Pulsed (Note 1) | I_{DM} | -30 | A |
| Maximum Power Dissipation | P_D | 1.4 | W |
| Operating Junction and Storage Temperature Range | T_J, T_{STG} | -55 To 150 | °C |

Thermal Characteristic

| | | | |
|--|-----------------|------|------|
| Thermal Resistance, Junction-to-Ambient (Note 2) | $R_{\theta JA}$ | 89.3 | °C/W |
|--|-----------------|------|------|

Electrical Characteristics (TA=25°C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Typ | Max | Unit |
|--------------------------------|------------|--------------------------------|-----|-----|-----|------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $V_{GS} = 0V, I_D = -250\mu A$ | -20 | | - | V |

| | | | | | | |
|---|--------------|---|-------|--------|----------|-----------|
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS}=-20V, V_{GS}=0V$ | - | - | 1 | μA |
| Gate-Body Leakage Current | I_{GSS} | $V_{GS}=\pm 10V, V_{DS}=0V$ | - | - | ± 10 | μA |
| On Characteristics (Note 3) | | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=-250\mu A$ | -0.35 | -0.65 | -0.9 | V |
| Drain-Source On-State Resistance | $R_{DS(ON)}$ | $V_{GS}=-4.5V, I_D=-4A$ | - | 29 | 36 | $m\Omega$ |
| | | $V_{GS}=-2.5V, I_D=-4A$ | - | 37 | 49 | $m\Omega$ |
| Forward Transconductance | g_{FS} | $V_{DS}=-5V, I_D=-4A$ | 8 | - | - | S |
| Dynamic Characteristics (Note4) | | | | | | |
| Input Capacitance | C_{iss} | $V_{DS}=-10V, V_{GS}=0V,$ $F=1.0MHz$ | - | 1181.1 | - | PF |
| Output Capacitance | C_{oss} | | - | 121.3 | - | PF |
| Reverse Transfer Capacitance | C_{rss} | | - | 114.8 | - | PF |
| Switching Characteristics (Note 4) | | | | | | |
| Turn-on Delay Time | $t_{d(on)}$ | $V_{DD}=-10V, R_L=2.5\Omega$ $V_{GS}=-4.5V, R_{GEN}=3\Omega$ | - | 12 | | nS |
| Turn-on Rise Time | t_r | | - | 10 | | nS |
| Turn-Off Delay Time | $t_{d(off)}$ | | - | 19 | | nS |
| Turn-Off Fall Time | t_f | | - | 25 | | nS |
| Total Gate Charge | Q_g | $V_{DS}=-10V, I_D=-4A,$ $V_{GS}=-4.5V$ | - | 10.2 | | nC |
| Gate-Source Charge | Q_{gs} | | - | 1.3 | - | nC |
| Gate-Drain Charge | Q_{gd} | | - | 2.4 | - | nC |
| Drain-Source Diode Characteristics | | | | | | |
| Diode Forward Voltage (Note 3) | V_{SD} | $V_{GS}=0V, I_S=-4A$ | - | - | -1.2 | V |
| Diode Forward Current (Note 2) | I_S | | - | - | -4 | A |

Notes:

1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, $t \leq 10$ sec.
3. Pulse Test: Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
4. Guaranteed by design, not subject to production

Typical Electrical and Thermal Characteristics

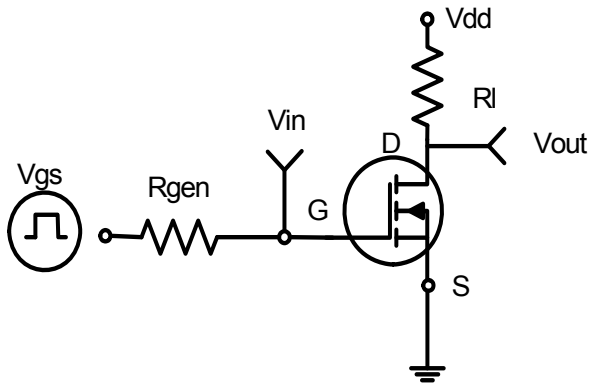


Figure 1: Switching Test Circuit

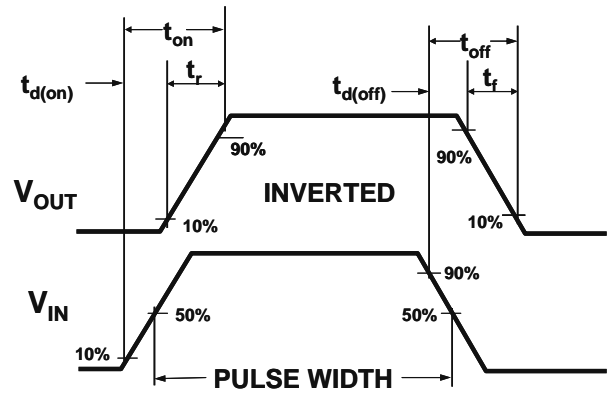


Figure 2: Switching Waveforms

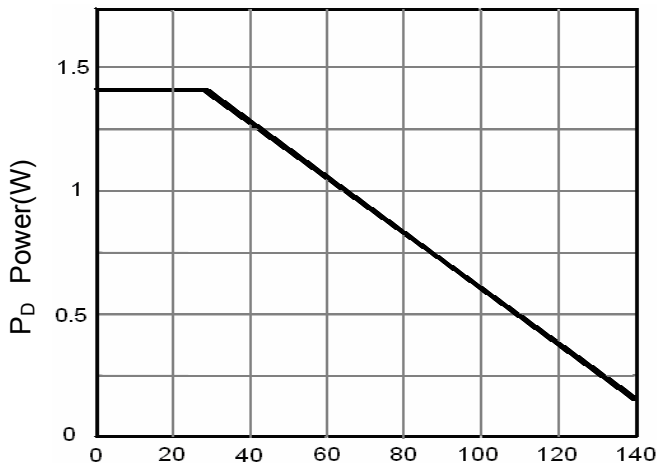


Figure 3 Power Dissipation

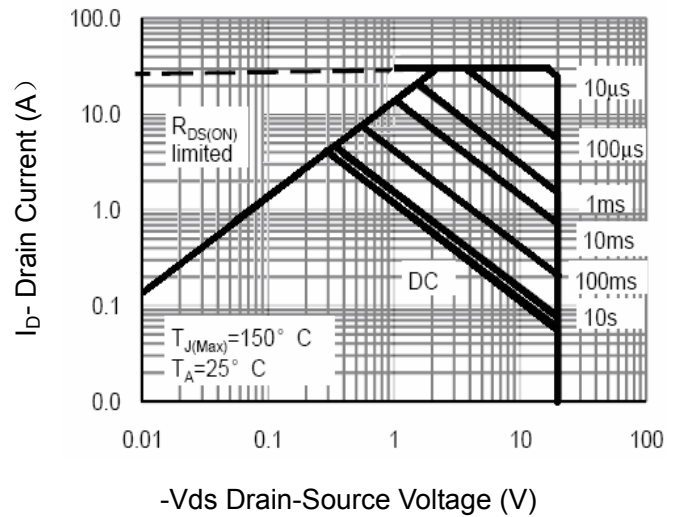


Figure 4 Safe Operation Area

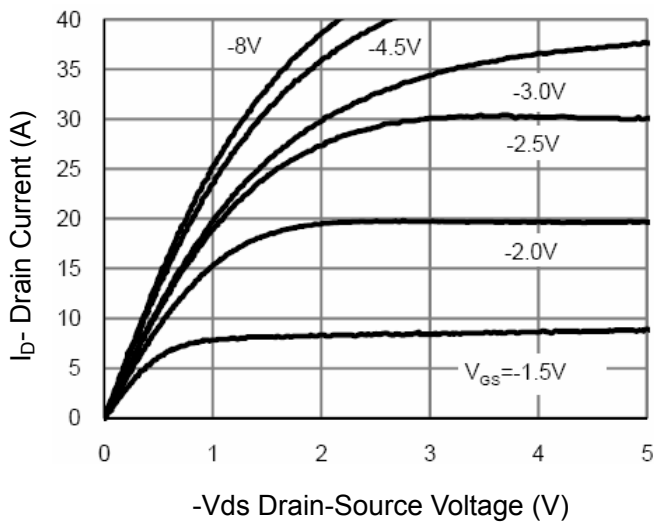


Figure 5 Output Characteristics

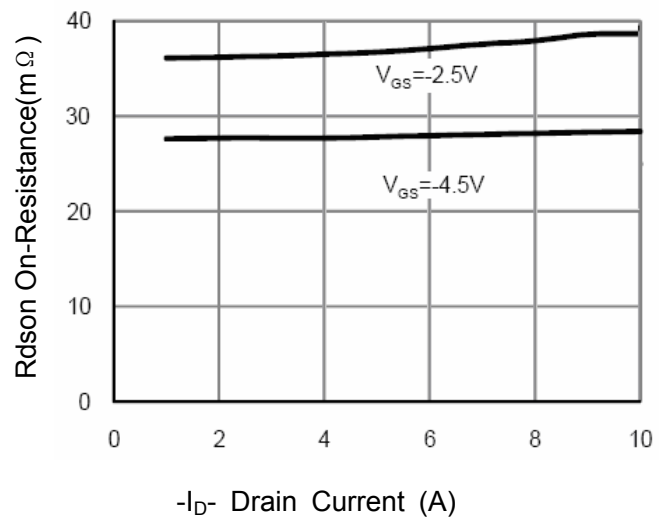


Figure 6 Drain-Source On-Resistance

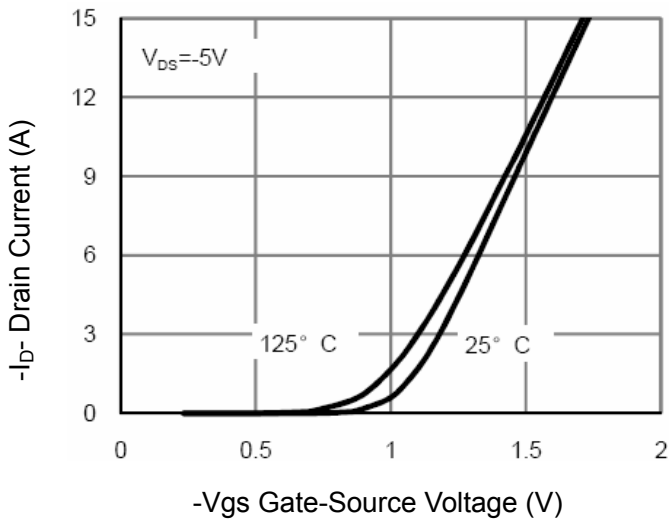


Figure 7 Transfer Characteristics

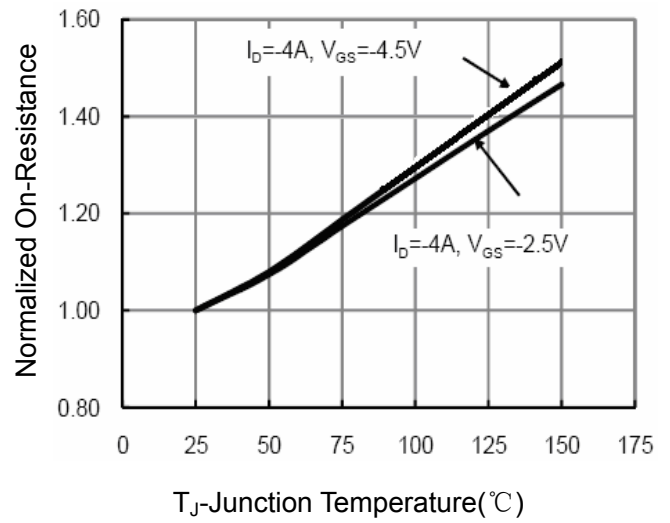


Figure 8 Drain-Source On-Resistance

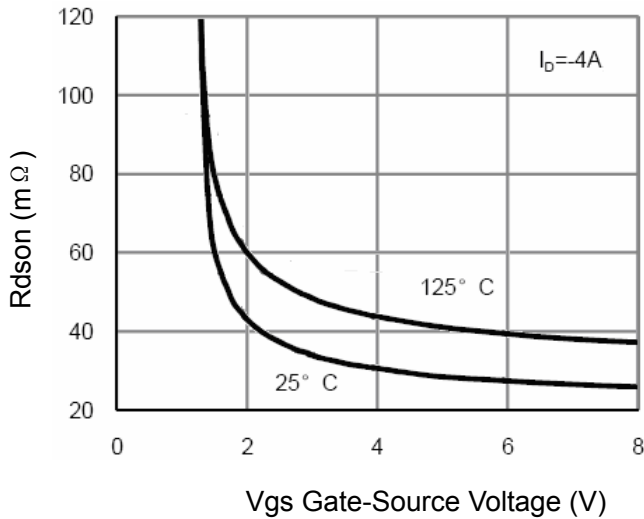


Figure 9 Rdson vs Vgs

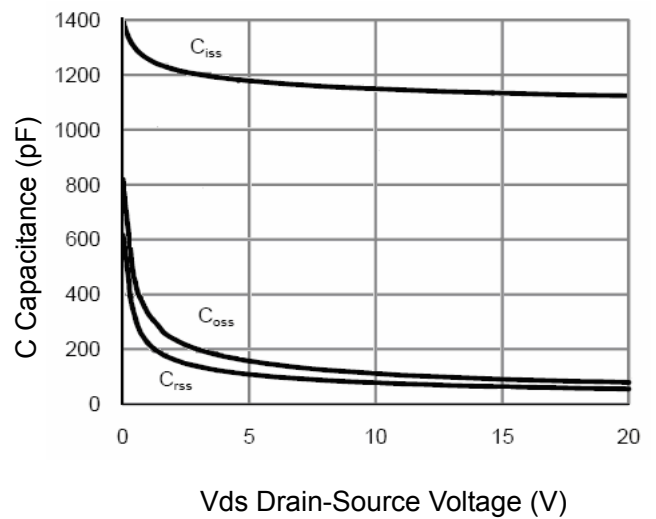


Figure 10 Capacitance vs Vds

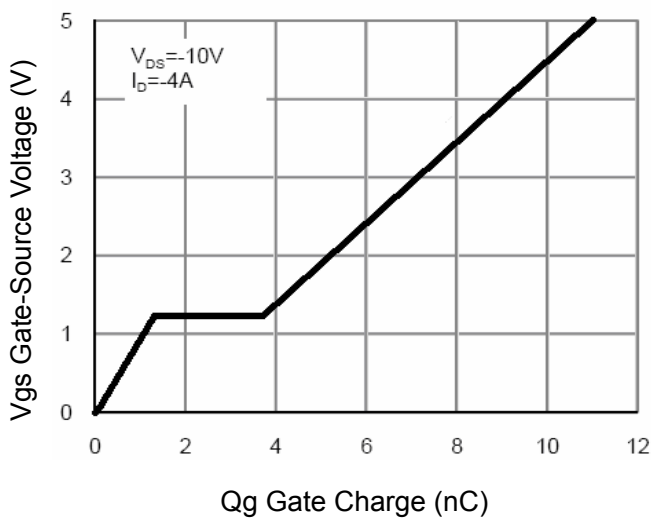


Figure 11 Gate Charge

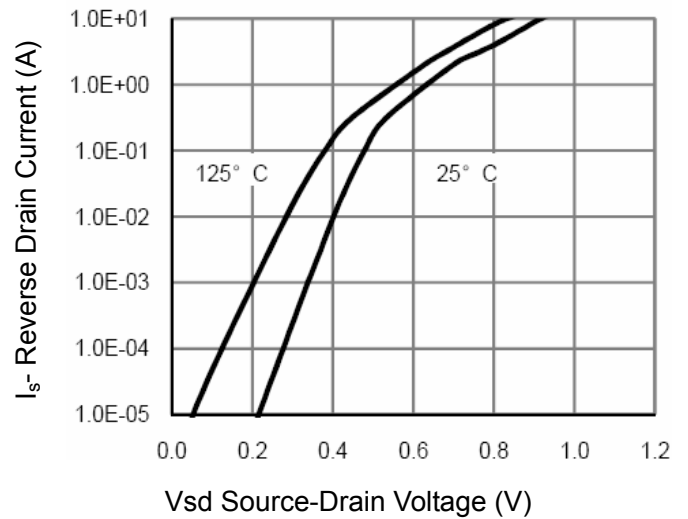


Figure 12 Source- Drain Diode Forward

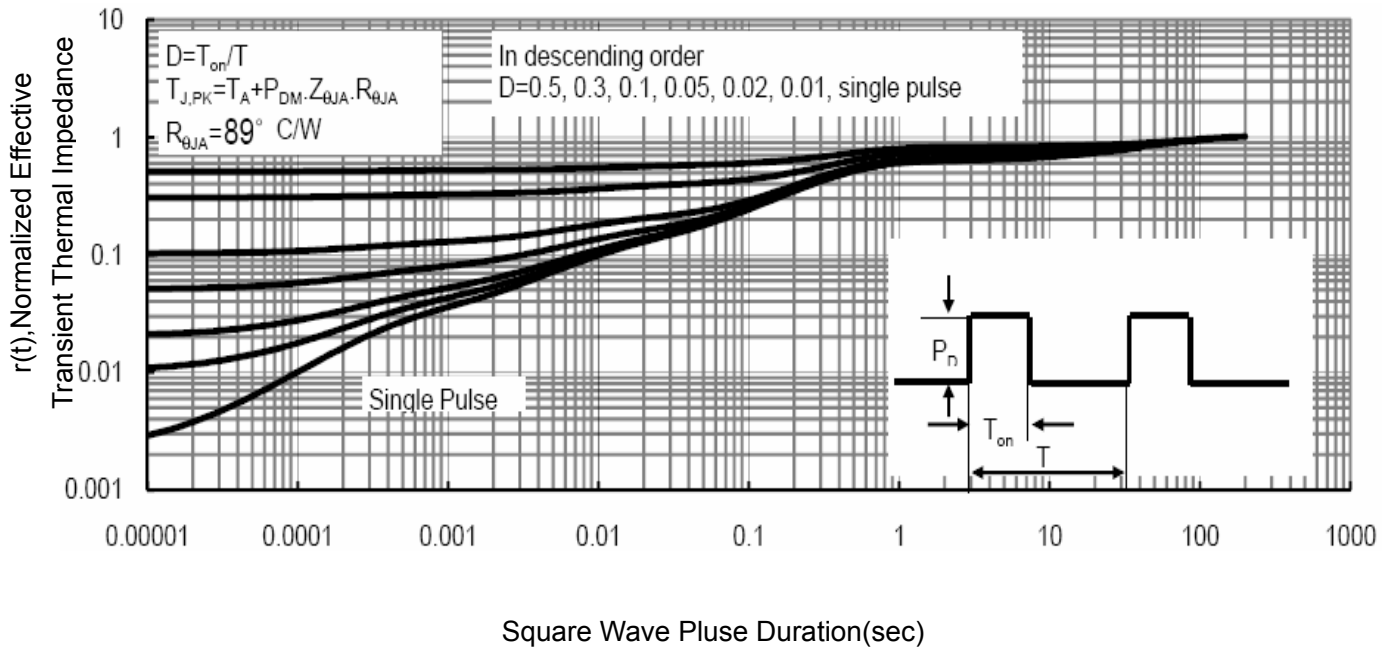
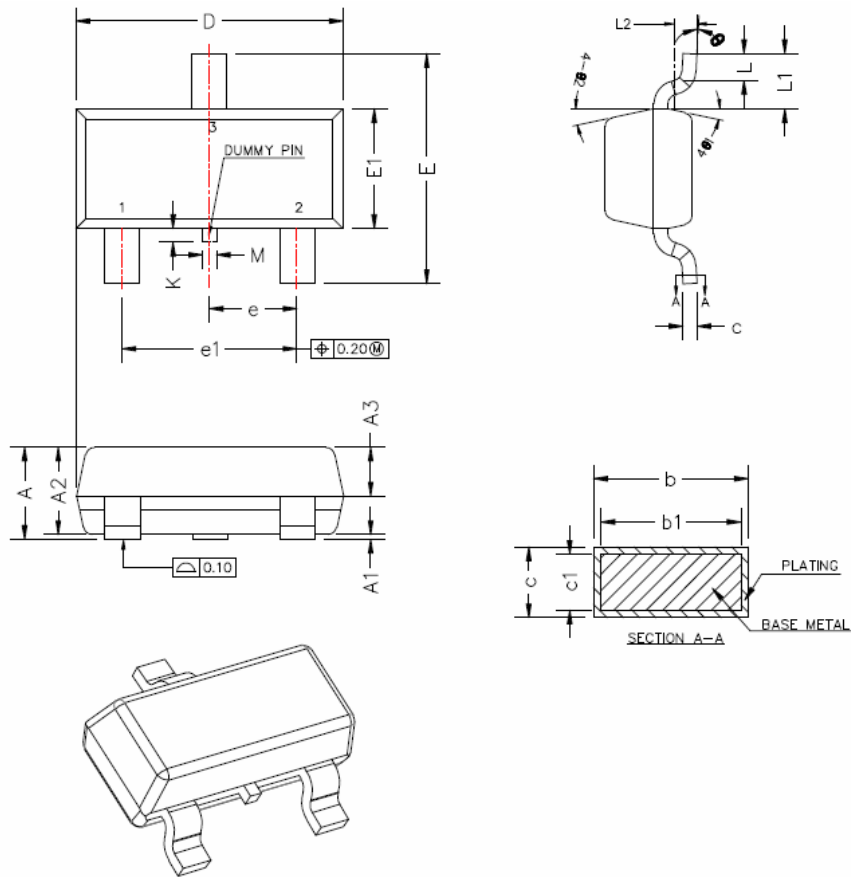


Figure 13 Normalized Maximum Transient Thermal Impedance

SOT-23 Package Information



| Symbol | Millimeters | |
|--------|-------------|------|
| | Min. | Max. |
| A | 0.89 | 1.12 |
| A1 | 0.01 | 0.10 |
| A2 | 0.88 | 1.02 |
| A3 | 0.43 | 0.63 |
| b | 0.36 | 0.50 |
| b1 | 0.35 | 0.45 |
| c | 0.14 | 0.20 |
| c1 | 0.14 | 0.16 |
| D | 2.80 | 3.00 |
| E | 2.35 | 2.64 |
| E1 | 1.20 | 1.40 |
| e | 0.90 | 1.00 |
| e1 | 1.80 | 2.00 |
| L | 0.40 | 0.60 |
| L1 | 0.6REF | |
| L2 | 0.25BSC | |
| θ | 0° | 8° |
| θ1 | 10° | 14° |
| θ2 | 10° | 14° |

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